

RS3A/B - RS3M/B

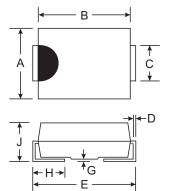
3.0A SURFACE MOUNT FAST RECOVERY RECTIFIER

Features

- Glass Passivated Die Construction
- Fast Recovery Time for High Efficiency
- Low Forward Voltage Drop and High Current Capability
- Surge Overload Rating to 100A Peak
- Ideally Suited for Automatic Assembly
- Lead Free Finish/RoHS Compliant (Note 4)

Mechanical Data

- Case: Molded Plastic
- Case Material: UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band or Cathode Notch
- Weight: SMB 0.093 grams (approx)
 - SMC 0.21 grams (approx)
- Marking: Type Number, See Page 3 Ordering Information: See Page 3



Dim	SN	ИB	SMC		
	Min	Max	Min	Max	
Α	3.30	3.94	5.59	6.22	
В	4.06	4.57	6.60	7.11	
С	1.96	2.21	2.75	3.18	
D	0.15	0.31	0.15	0.31	
E	5.00	5.59	7.75	8.13	
G	0.10	0.20	0.10	0.20	
Н	0.76	1.52	0.76	1.52	
J	2.00	2.62	2.00	2.62	
All Dimensions in mm					

AB, BB, DB, GB, JB, KB, MB Suffix Designates SMB Package A, B, D, G, J, K, M Suffix Designates SMC Package

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		Symbol	RS3 A/AB	RS3 B/BB	RS3 D/DB	RS3 G/GB	RS3 J/JB	RS3 K/KB	RS3 M/MB	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage		V _{R(RMS)}	35	70	140	280	420	560	700	V
Average Rectified Output Current	@ T _T = 75°C	Io				3.0				Α
Non-Repetitive Peak Forward Surge Curr 8.3ms Single half sine-wave Superimpose (JEDEC Method)	ent ed on Rated Load	I _{FSM}				100				А
Forward Voltage	@ $I_F = 3.0A$	V_{FM}				1.3				V
Peak Reverse Current at Rated DC Blocking Voltage	@ T _A = 25°C @ T _A = 125°C	I _{RM}				5.0 250				μА
Maximum Recovery Time (Note 3)		t _{rr}		15	50		250	50	00	ns
Typical Junction Capacitance (Note 2)		Cj	50					pF		
Typical Thermal Resistance Junction to Terminal (Note 1)		$R_{\theta JT}$	25						K/W	
Operating and Storage Temperature Range		T _{j,} T _{STG}	-65 to +150					°C		

- 1. Thermal resistance: junction to terminal, unit mounted on PC board with 5.0 mm² (0.013 mm thick) copper pad as heat sink.
- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. Reverse recovery test conditions: I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A. See figure 5.
- 4. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.

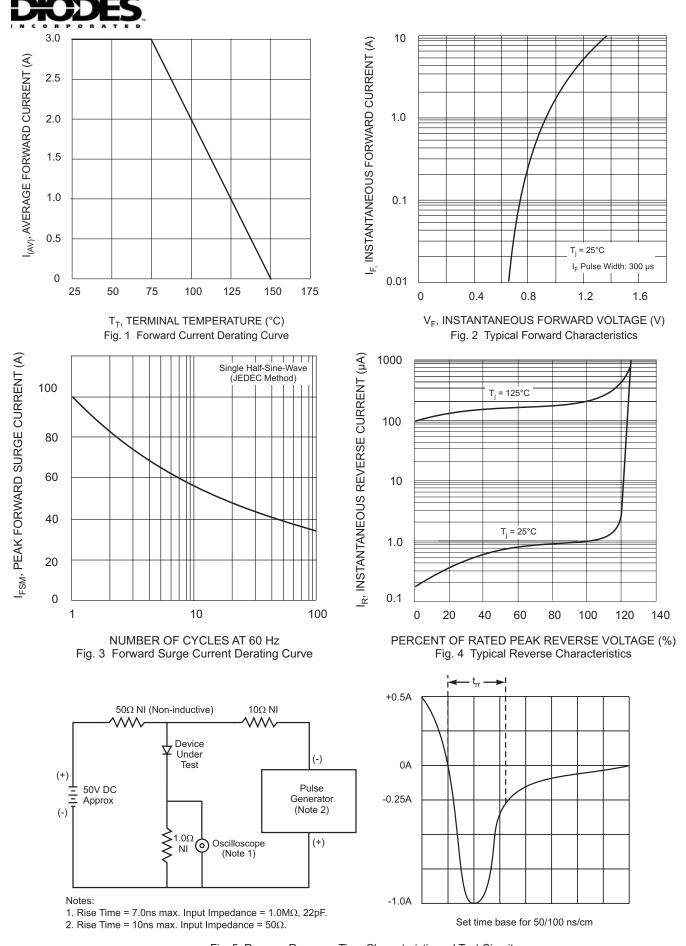


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit



Ordering Information (Note 5)

Device*	Packaging	Shipping
RS3x-13-F	SMC	3000/Tape & Reel
RS3xB-13-F	SMB	3000/Tape & Reel

^{*} x = Device type, e.g. RS3A-13-F (SMC package); RS3AB-13-F (SMB package).

Notes: 5. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



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